

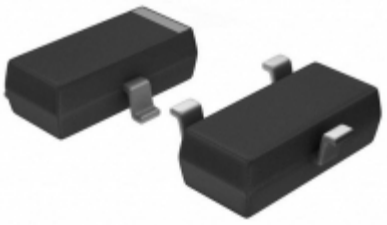


|   |  |
|---|--|
|  | <p><b>SI2342DS-T1-GE3</b></p>  |
|   | <p><b>Hersteller-Teilenummer:</b> <a href="#">SI2342DS-T1-GE3</a></p> <p><b>Hersteller / Marke:</b> <a href="#">Vishay / Siliconix</a></p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 8V 6A SOT-23</p> <p><b>Datenblätter:</b>  <a href="#">SI2342DS-T1-GE3.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 156815 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p> |
|  |  |
| <p>Image may be representation.<br/>See specs for product details.</p>            |  |

Spezifikationen

|  |   |
|--|---|
| Teilenummer                                      | <a href="#">SI2342DS-T1-GE3</a>                                     |
| Hersteller                                       | <a href="#">Vishay / Siliconix</a>                                  |
| Beschreibung                                     | MOSFET N-CH 8V 6A SOT-23  |
| Kategorie  | <a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a> |
| Teilstatus                                       | 156815 pcs Stock  |
| Serie  | TrenchFET®  |
| Technologie                                      | MOSFET (Metal Oxide)  |
| Betriebstemperatur                               | -55°C ~ 150°C (TJ)  |
| Befestigungsart                                  | Surface Mount   |
| Verpackung / Gehäuse                             | TO-236-3, SC-59, SOT-23-3   |
| Supplier Device-Gehäuse                          | SOT-23  |
| Verlustleistung (max)                            | 1.3W (Ta), 2.5W (Tc)  |
| Typ FET  | N-Channel   |
| FET-Merkmal                                      | -   |
| Drain-Source-Spannung (Vdss)                     | 8V  |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 6A (Tc)   |
| Rds On (Max) @ Id, Vgs                           | 17 mOhm @ 7.2A, 4.5V  |
| VGS (th) (Max) @ Id                              | 800mV @ 250µA   |
| Gate Charge (Qg) (Max) @ Vgs                     | 15.8nC @ 4.5V   |
| Eingabekapazität (Ciss) (Max) @ Vds              | 1070pF @ 4V   |
| Antriebsspannung (Max Rds On, Min Rds On)        | 1.2V, 4.5V  |
| Vgs (Max)  | ±5V   |
| Verpackung                                       | Tape & Reel (TR)  |



















































SI2342DS-T1-GE3 ist neu im Original, Suche SI2342DS-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI2342DS-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI2342DS-T1-GE3: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

|   |  |   |   |
|---|--|---|---|
|  <p><b>SI2343CDS-T1-GE3</b><br/>Electro-Films (EFI) / Vishay<br/>MOSFET P-CH 30V 5.9A SOT-23</p> |  <p><b>SI2342DS-T1-GE3</b><br/>Vishay / Spectrol<br/>MOSFET N-CH 8V 6A SOT-23</p>     |  <p><b>SI2341DS-T1-GE3</b><br/>Electro-Films (EFI) / Vishay<br/>MOSFET P-CH 30V 2.5A SOT-23</p> |  <p><b>SI2341DS-T1-E3</b><br/>Electro-Films (EFI) / Vishay<br/>MOSFET P-CH 30V 2.5A SOT-23</p> |
|  <p><b>SI2343CDS</b><br/>VISHAY<br/>SI2343CDS VISHAY</p>   |  <p><b>SI2341DS-T1-GE3</b><br/>Vishay / Siliconix<br/>MOSFET P-CH 30V 2.5A SOT-23</p> |  <p><b>SI2343CDS-T1-E3</b><br/>VISHAY<br/>SI2343CDS-T1-E3 VISHAY</p>                            |  <p><b>SI2342DS-T1-E3</b><br/>VISHAY<br/>SI2342DS-T1-E3 VISHAY</p>                             |

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|--|---|---|---|--|
|  SI2334DS-T1-GE3  |  SI2334DS-T1-GE3 |  SI2335DS-T1     |  SI2335DS-T1-E3   |  SI2335DS-T1-E3   |
|  SI2335DS-T1-GE3  |  SI2335DS-T1-GE3 |  SI2336DS-T1-E3  |  SI2336DS-T1-GE3  |  SI2336DS-T1-GE3  |
|  SI2337DS         |  SI2337DS-T1-E3  |  SI2337DS-T1-E3  |  SI2337DS-T1-GE3  |  SI2337DS-T1-GE3  |
|  SI2338DS-T1-E3   |  SI2338DS-T1-GE3 |  SI2338DS-T1-GE3 |  SI2341DS         |  SI2341DS-T1-E3   |
|  SI2341DS-T1-E3   |  SI2341DS-T1-GE3 |  SI2341DS-T1-GE3 |  SI2342DS-T1-E3   |  SI2342DS-T1-GE3  |
|  SI2343ADS-T1-GE3 |  SI2343CDS       |  SI2343CDS-T1-E3 |  SI2343CDS-T1-GE3 |  SI2343CDS-T1-GE3 |
|  SI2343DS-T1-E3   |  SI2343DS-T1-E3  |  SI2343DS-T1-GE3 |  SI2343DS-T1-GE3  |  SI2344DS-E3      |
|  SI2347DS-T1-GE3  |  SI2347DS-T1-GE3 |  SI2351DS-T1-E3  |  SI2351DS-T1-E3   |  SI2351DS-T1-GE3  |
|  SI2351DS-T1-GE3  |  SI2356DS-T1-GE3 |  SI2356DS-T1-GE3 |  SI2365EDS        |  SI2365EDS-T1-GE3 |
|  SI2365EDS-T1-GE3 |  SI2366DS-T1-E3  |  SI2366DS-T1-GE  |  SI2366DS-T1-GE3  |  SI2366DS-T1-GE3  |

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